Product data sheet

1. General description

Hyperfast power diode in a TO252(DPAK) plastic package





2. Features and benefits

- Low leakage current
- · Low thermal resistance
- · Low reverse recovery current
- · Reduces switching losses in associated MOSFET or IGBT
- · Package meets UL94 V0 which guaranteed by Epoxy Mold Compound

3. Applications

- Active PFC in air conditioner/EV charger/PV
- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- · Half-bridge/full-bridge switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit				
Absolute maximum rating											
V_{RRM}	repetitive peak reverse voltage				V						
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 115$ °C; Fig. 1; Fig. 2; Fig. 3		15			А				
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 115 °C; square-wave pulse		30			A				
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; <u>Fig. 4</u>		150			А				
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		165			Α				
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit				
Static ch	aracteristics										
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.92	2.35	V				
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.27	1.70	V				
Dynamic characteristics											
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 200 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7		-	16	-	ns				

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		K — K — A
2	K	cathode [1]		001aaa020
3	А	anode		
mb	К	mounting base; connected to cathode		

^[1] It is not possible to connect to pin 2 of the TO252 package.

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing guantity	Package version	Package issue date
BYC15MD-600P	TO252	BYC15MD-600PJ	Reel	2500	TO252d	07-Sep-2022

7. Marking

Table 4. Marking codes

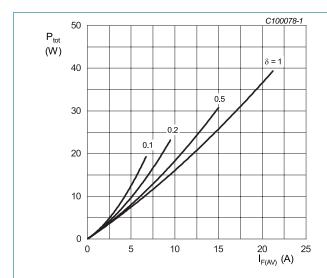
Type number	Marking codes
BYC15MD-600P	BYC15MD 600P

8. Limiting values

Table 5. Limiting values

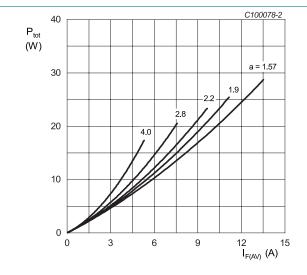
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			600	V
V_{RWM}	crest working reverse voltage			600	V
V_R	reverse voltage	DC		600	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 115 °C; Fig. 1; Fig. 2; Fig. 3		15	А
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 115 °C; square-wave pulse		30	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		150	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		165	А
T _{stg}	storage temperature			-65 to 175	°C
T _j	junction temperature			-65 to 175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 1.384 \text{ V; R}_s = 0.0223 \text{ }\Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 1.384 V; R_s = 0.0223 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

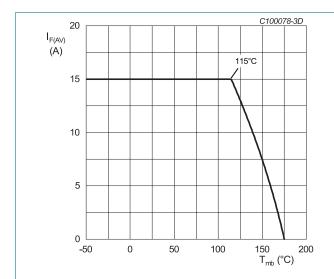


Fig. 3. Forward current as a function of mounting base temperature; maximum values

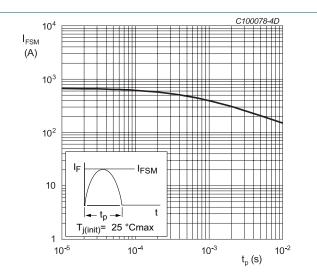


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5		-	-	1.96	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W

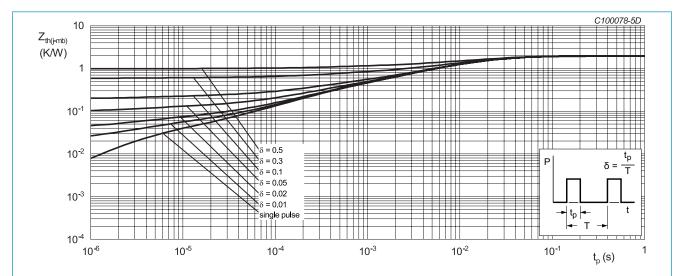
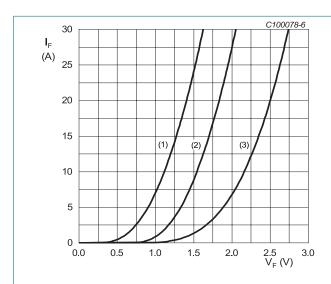


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V_{F}	forward voltage	I _F = 15 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.92	2.35	V
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.27	1.70	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C		-	0.71	10	μA
		V _R = 600 V; T _j = 150 °C		-	-	0.5	mA
Dynamic	characteristics						
Q _r	reverse charge	$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	75	-	nC
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	204	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	16	-	ns
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_i = 25 \text{ °C}; Fig. 7$		-	26	-	ns
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_i = 125 \text{ °C}; Fig. 7$		-	38	-	ns
I _{RM}	peak reverse recovery current	$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/µs};$ $T_1 = 25 \text{ °C}; Fig. 7$		-	5.7	-	А
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_i = 125 \text{ °C}; Fig. 7$		-	10.8	-	А



 V_o = 1.384 V; R_s = 0.0223 Ω

(1) T_i = 150 °C; typical values

(2) T_j = 150 °C; maximum values

(3) T_i = 25 °C; maximum values



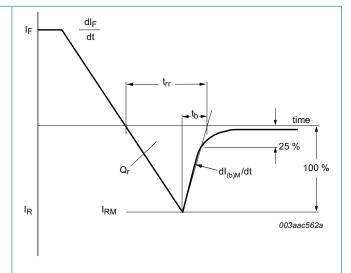
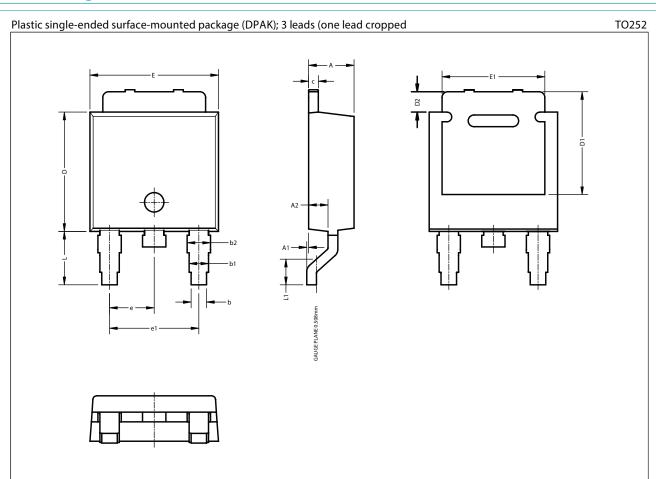


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline



Note:

1. All dimensions do not include mold flash & gate remain and metal protrusion.

Uni	t	Α	A 1	A2	b	b1	b2	С	D	D1	D2	E	E1	е	e1	L	L1
mm no		2.16	0.00	0.90	0.70	0.86	1.06	0.46	5.97	5.05	0.98	6.45	5.20	2.30	4.60	2.60	1.25
		2.41	0.10	1.10	0.90	1.11	1.32	0.58	6.22	5.35	1.18	6.75	5.40			2.90	1.65

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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